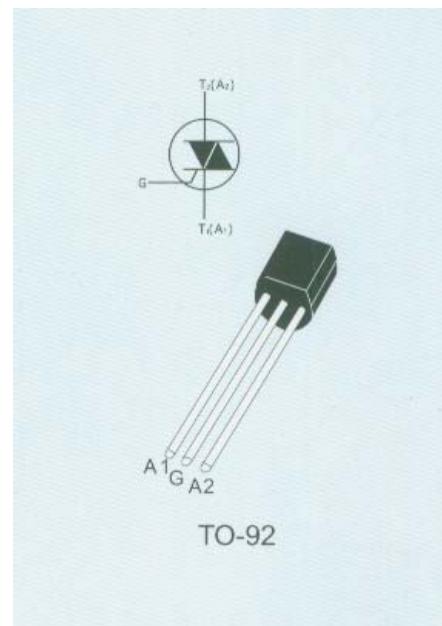


STANDARD

1A TRIACs

### ■ MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	1	A
$V_{(DRM)}/V_{RRM}$	400 to 600	V
$I_{GT(Q1)}$	3 to 25	mA



### ■ GENERAL DESCRIPTION

The MAC97A6 series is suitable for general purpose AC switching applications. They can be found in applications such as home appliances (electro-valve, pump, door lock, small lamp control), fan speed controllers,

Different gate current sensitivities are available, allowing optimized performances when controlled directly from micro-controllers.

### ■ ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-92	1	A
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial=25°C)	F=50Hz	8	A
		F=60Hz	8.5	
$I^2T$	$I^2T$ Value for fusing	tp=10ms	0.35	$A^2s$
$dl/dt$	Critical rate of rise of on-state current $I_G=2 \times I_{GT}$ , $tr \leq 100\text{ns}$	F=120Hz	20	$A/\mu s$
$I_{GM}$	Peak gate current	tp=20μs	1	A
$P_{G(AV)}$	Average gate power dissipation	$T_j=125^\circ\text{C}$	0.1	W
$T_{stg}$ $T_j$	Storage junction temperature range Operating junction temperature range		-40 to +150 -40 to +125	°C

## ■ STATIC CHARACTERISTICS

T<sub>j</sub>=25°C unless otherwise stated

Symbol	Test Conditions	Quadrant	Value		Unit
			Typ	Max	
I <sub>GT</sub> <sup>(1)</sup>	V <sub>D</sub> =12V R <sub>L</sub> =30Ω	I-II-III	5	10	mA
		IV	7	10	
V <sub>GT</sub>		ALL	MAX.	1.5	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> R <sub>L</sub> =3.3KΩ T <sub>j</sub> =125°C	ALL	MIN.	0.2	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> =50mA		MAX.	10 25	mA
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	I-III-IV	10	25	mA
		II	20	50	
V <sub>TM</sub> <sup>(2)</sup>	I <sub>TM</sub> =1.4A tp=380μs	T <sub>j</sub> =25°C	MAX.	1.6	V
V <sub>t0</sub> <sup>(2)</sup>	Threshold voltage	T <sub>j</sub> =125°C	MAX.	0.95	V
R <sub>d</sub> <sup>(2)</sup>	Dynamic resistance	T <sub>j</sub> =125°C	MAX.	400	mΩ
I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> =V <sub>RRM</sub>	T <sub>j</sub> =25°C	MAX.	50	μA
		T <sub>j</sub> =125°C		0.5	mA

## ■ DYNAMIC CHARACTERISTICS

Symbol	Test Condition		Typ	Max	Unit
dV/dt <sup>(2)</sup>	V <sub>D</sub> =67% V <sub>DRM</sub> gate open T <sub>j</sub> =110°C	MIN	50	100	V/μs
(dV/dt)c <sup>(2)</sup>	(dI/dt)c=0.44A/ms T <sub>j</sub> =110°C	MIN	2	5	V/μs

**Note1:** minimum I<sub>GT</sub> is guaranteed at 5% of I<sub>GT</sub> max.

**Note2:** for both polarities of A2 referenced to A1.

## ■ THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th(j-l)</sub>	Junction to lead (AC)	TO-92	60
R <sub>th(j-a)</sub>	Junction to ambient	TO-92	150

## PERFORMANCE CURVES

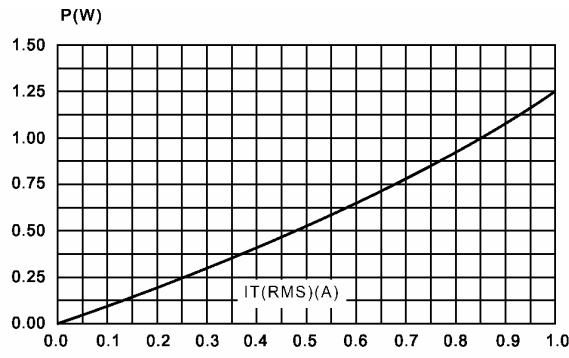


Fig.1. Maximum power dissipation versus RMS  
on-state current (full cycle)

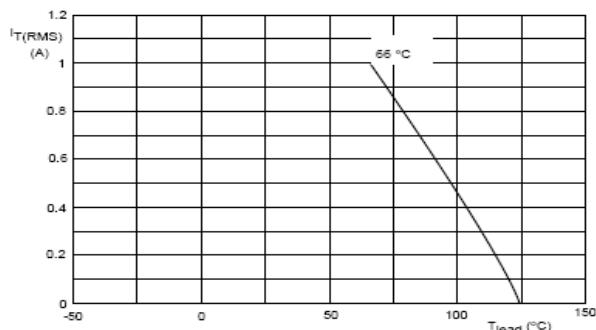


Fig.4. RMS on-state current versus ambient  
temperature (full cycle)

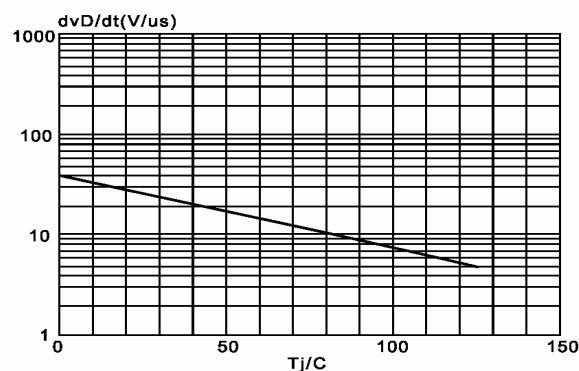


Fig.2. Typical, critical rate of rise off-state voltage,  
 $dV_D/dt$  versus junction temperature  $T_j$

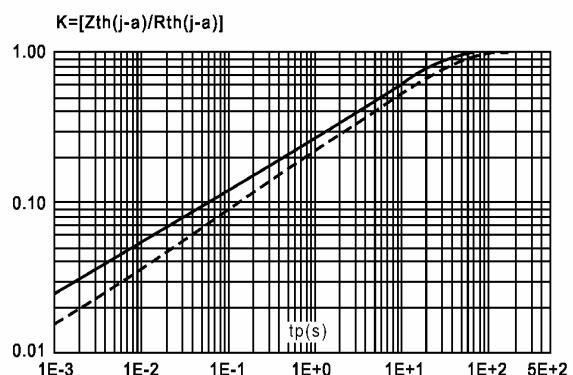


Fig.5. Relative variation of thermal impedance  
junction to ambient versus pulse duration

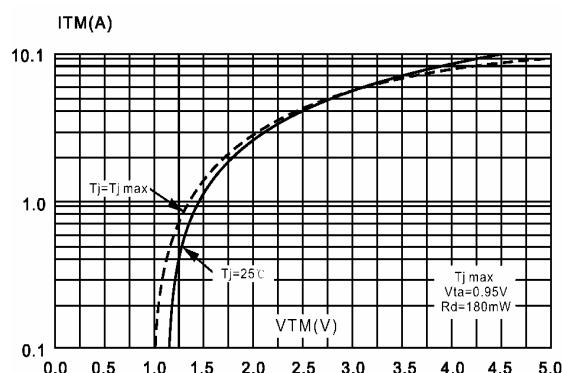


Fig.3. On-state characteristics (maximum values),  
 $IT_M$  (A) versus  $V_{TM}$  (V)

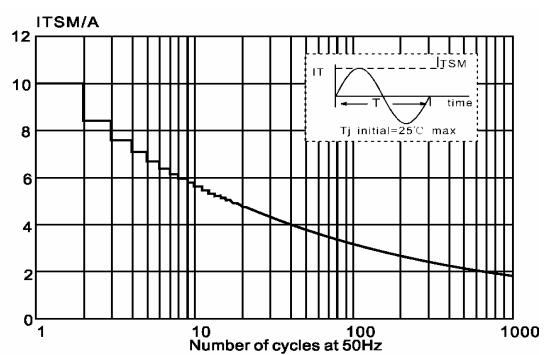


Fig.6. Maximum permissible non-repetitive peak  
on-state current  $I_{TSM}$  versus number of cycles,  
for sinusoidal currents,  $f=50\text{Hz}$

## PERFORMANCE CURVES

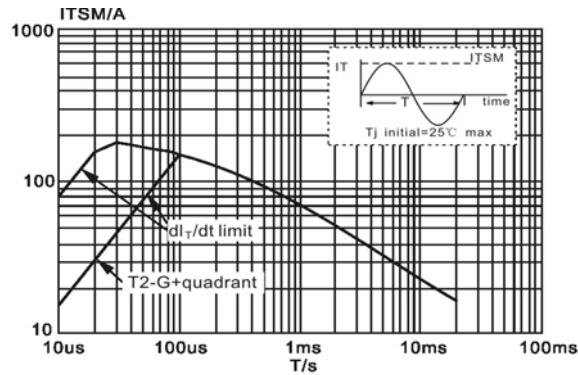


Fig.7. Maximum permissible non-repetitive peak  
on-state current  $I_{TSM}$  versus pulse width  $t_p$ ,  
for sinusoidal currents,  $t_p \leq 20\text{ms}$

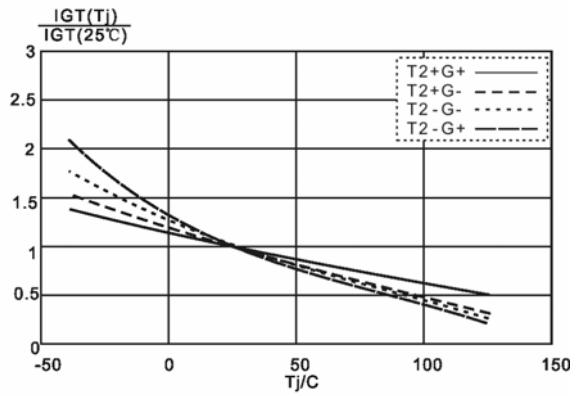


Fig.10. Normalized gate trigger current  $I_{GT}(T_j)/I_{GT}(25^\circ\text{C})$ ,  
versus junction temperature  $T_j$

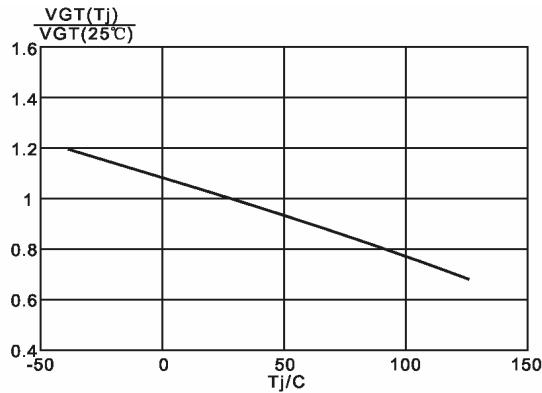


Fig.8. Normalized gate trigger voltage  $V_{GT}(T_j)/V_{GT}(25^\circ\text{C})$ ,  
versus junction temperature  $T_j$

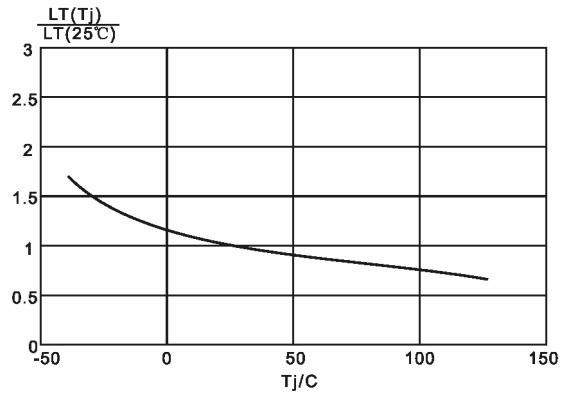


Fig.11. Normalized latching current  $I_{LT}(T_j)/I_{LT}(25^\circ\text{C})$ ,  
versus junction temperature  $T_j$

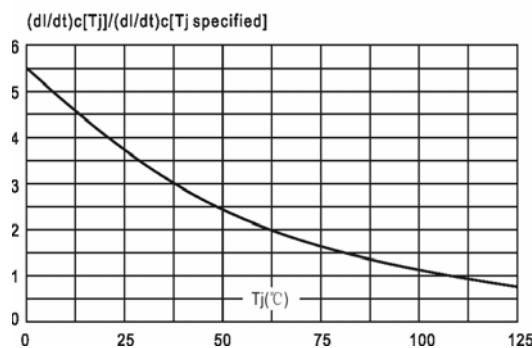


Fig.9. Relative variation of critical rate of decrease of  
main current versus junction temperature  $T_j$

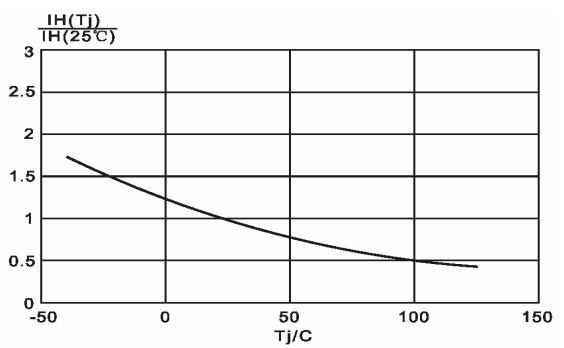
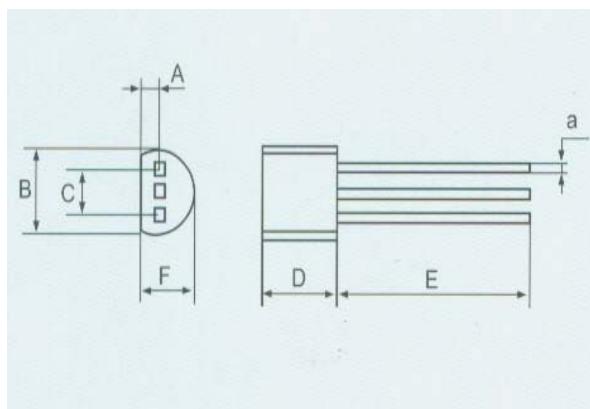


Fig.12. Normalized holding current  $I_H(T_j)/I_H(25^\circ\text{C})$ ,  
versus junction temperature  $T_j$

## PACKAGE MECHANICAL DATA

TO-92(Plastic)



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		1.35			0.053	
B			4.70			0.185
C		2.54			0.100	
D	4.40			0.173		
E	12.70			0.500		
F			3.70			0.146
a			0.45			0.017